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Thank you for your cooperation and understanding,

WeEn Semiconductors





# ACT102H-600D AC Thyristor power switch 20 August 2014

**Product data sheet** 

## 1. General description

An AC Thyristor power switch with very high noise immunity and over-voltage protection configured for negative gate triggering in a SOT96-1 (SO8) small surface-mountable plastic package

## 2. Features and benefits

- Exclusive negative gate triggering
- Full cycle AC conduction
- High noise immunity
- · Remote gate separates the gate driver from the effects of the load current
- Surface-mountable package
- Very sensitive gate for lowest gate trigger current
- Safe clamping of low energy over-voltage transients
- Self-protective turn-on during high energy voltage transients

## 3. Applications

- Fan motor circuits
- Pump motor circuits
- Lower-power highly inductive, resistive and safety loads

## 4. Quick reference data

Symbol	Parameter	Conditions	M	in	Тур	Max	Unit
V <sub>DRM</sub>	repetitive peak off- state voltage		-		-	600	V
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 3}; \text{ Fig. 4}$	-		-	8	A
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; $T_{amb} \le 100 \text{ °C}$ ; Fig. 1; Fig. 2	-		-	0.2	A
V <sub>PP</sub>	peak pulse voltage	$T_j \le 25 \text{ °C}$ ; non-repetitive, off-state; Fig. 5	-		-	2	kV
Static chara	acteristics	·				_	
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 100 mA; LD+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	0	.5	-	5	mA





# ACT102H-600D

#### AC Thyristor power switch

Symbol	Parameter	Conditions	M	/lin	Тур	Max	Unit
		$V_D = 12 \text{ V}; \text{ I}_T = 100 \text{ mA}; \text{ LD- G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	0	).5	-	5	mA
V <sub>CL</sub>	clamping voltage	$I_{CL}$ = 0.1 mA; $t_p$ = 1 ms; $T_j \le$ 125 °C	6	650	-	-	V

# 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected	8	LD
2	LD	Load		
3	n.c.	not connected		G <b>⊸o</b> ∐≓⊣ CM
4	n.c.	not connected		001aaj924
5	G	Gate	SO8 (SOT96-1)	
6	СМ	Common		
7	СМ	Common		
8	n.c.	not connected		

# 6. Ordering information

Table 3. Ordering in	formation		
Type number	Package		
	Name	Description	Version
ACT102H-600D	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1

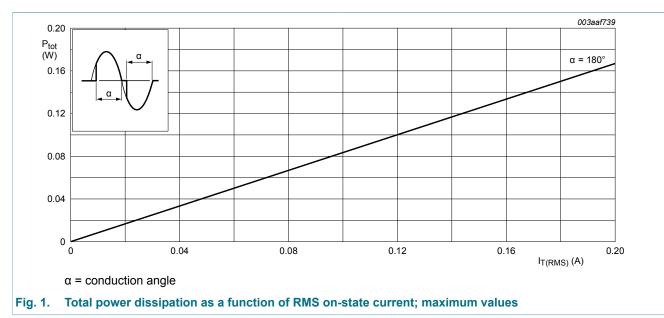
AC Thyristor power switch

## 7. Limiting values

#### Table 4.Limiting values

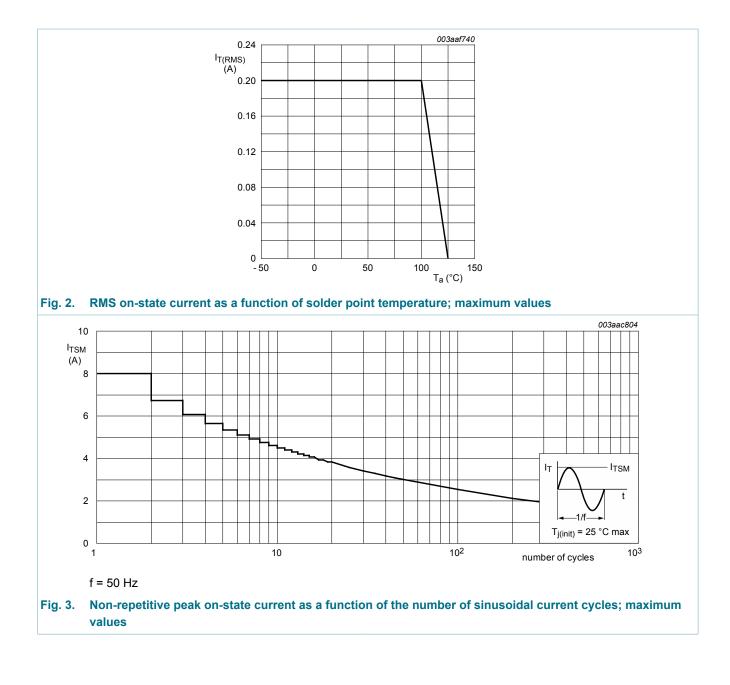
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	600	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>amb</sub> ≤ 100 °C; <u>Fig. 1;</u> <u>Fig. 2</u>	-	0.2	A
I <sub>TSM</sub>	non-repetitive peak on-state current	full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms	-	8.8	A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 20 ms; <u>Fig. 3; Fig. 4</u>	-	8	A
l <sup>2</sup> t	I2t for fusing	t <sub>p</sub> = 10 ms; SIN	-	0.31	A <sup>2</sup> s
dl <sub>T</sub> /dt	rate of rise of on-state current	$I_T$ = 1 A; $I_G$ = 20 mA; $dI_G/dt$ = 0.2 A/µs	-	50	A/µs
I <sub>GM</sub>	peak gate current	t = 20 µs	-	1	А
P <sub>GM</sub>	peak gate power		-	2	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.1	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C
V <sub>PP</sub>	peak pulse voltage	$T_j \le 25$ °C; non-repetitive, off-state; Fig. 5	-	2	kV



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#### AC Thyristor power switch

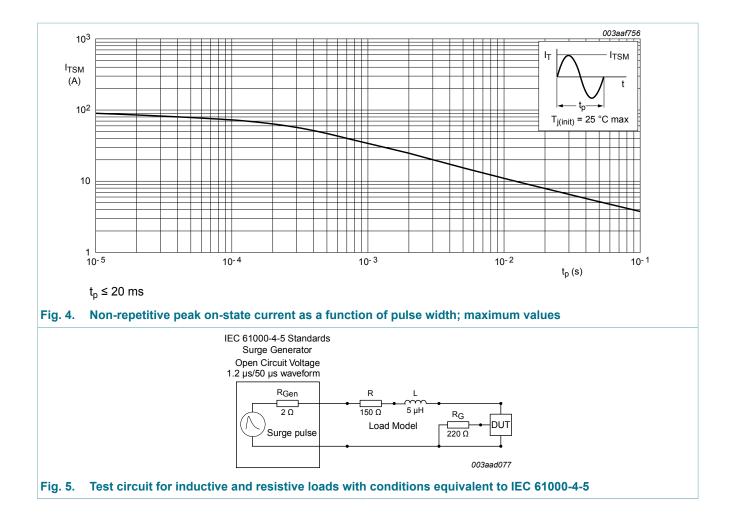


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#### AC Thyristor power switch

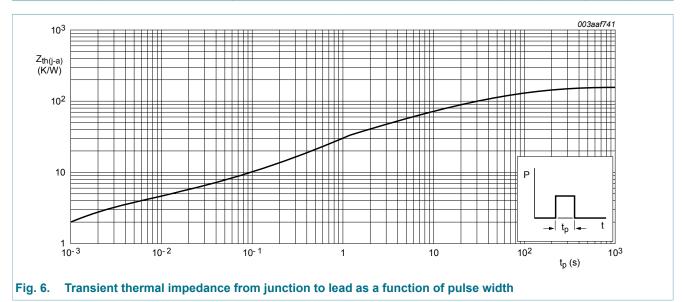


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### 8. Thermal characteristics

Table 5. The	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	full cycle; <u>Fig. 6</u>	-	150	-	K/W



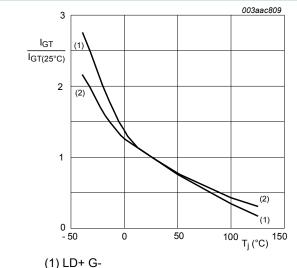
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## 9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static char	acteristics	· · · ·				
I <sub>GT</sub>	gate trigger current	$V_D$ = 12 V; I <sub>T</sub> = 100 mA; LD+ G-; T <sub>j</sub> = 25 °C; Fig. 7	0.5	-	5	mA
		$V_D$ = 12 V; I <sub>T</sub> = 100 mA; LD- G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	0.5	-	5	mA
I <sub>L</sub> latch	latching current	V <sub>D</sub> = 12 V; I <sub>G</sub> = 100 mA; LD+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	-	25	mA
		$V_D$ = 12 V; I <sub>G</sub> = 100 mA; LD- G-; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	-	25	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	20	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 0.3 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	-	1.2	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 400 V; I <sub>T</sub> = 100 mA; T <sub>j</sub> = 125 °C	0.15	-	-	V
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 100 mA; T <sub>j</sub> = 25 °C	-	-	0.9	V
ID	off-state current	V <sub>D</sub> = 600 V; T <sub>j</sub> = 25 °C	-	-	2	μA
		V <sub>D</sub> = 600 V; T <sub>j</sub> = 125 °C	-	-	0.2	mA
V <sub>CL</sub>	clamping voltage	I <sub>CL</sub> = 0.1 mA; t <sub>p</sub> = 1 ms; T <sub>j</sub> ≤ 125 °C	650	-	-	V
Dynamic cl	harateristics	1 I				
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; T <sub>j</sub> = 125 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit; Fig. 11	300	-	-	V/µs
dl <sub>com</sub> /dt	rate of change of commutating current	$V_D$ = 400 V; T <sub>j</sub> = 125 °C; I <sub>T(RMS)</sub> 1 A; dV <sub>com</sub> /dt = 15 V/µs; gate open circuit; Fig. 12; Fig. 13	0.15	-	-	A/ms

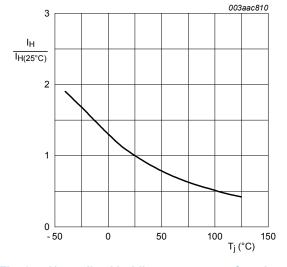
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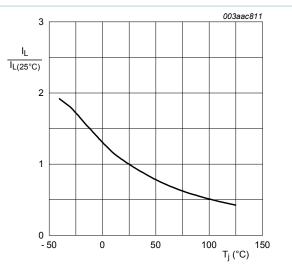




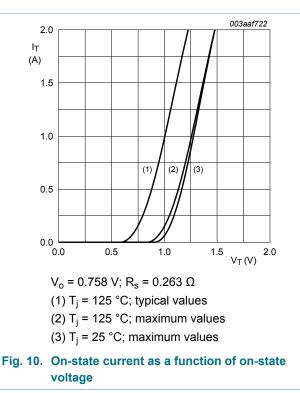










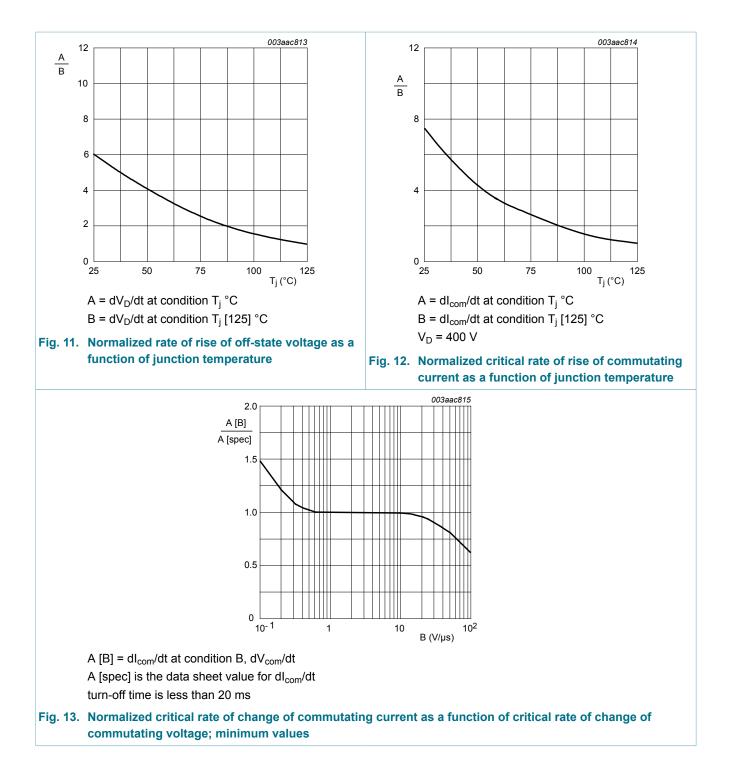


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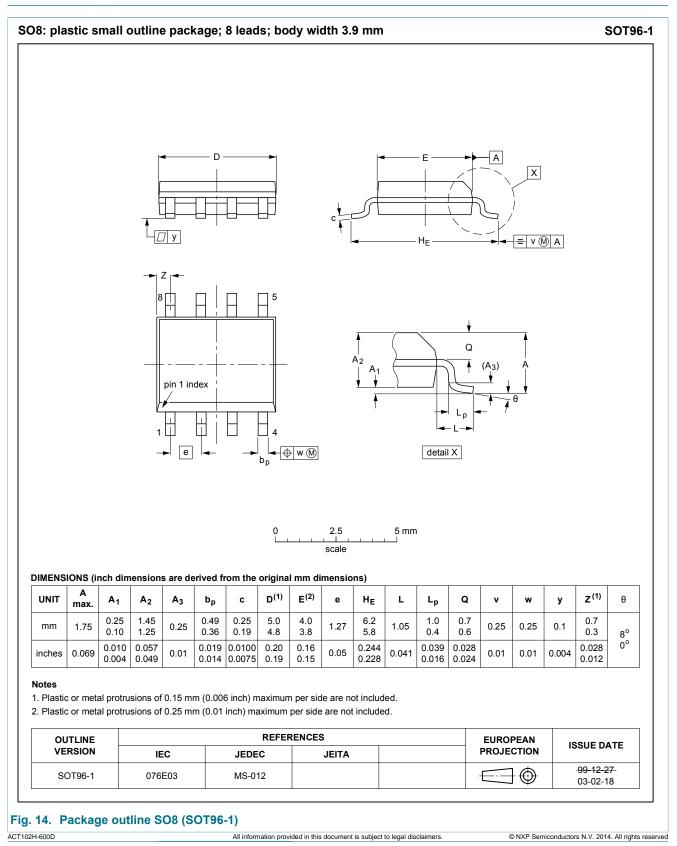
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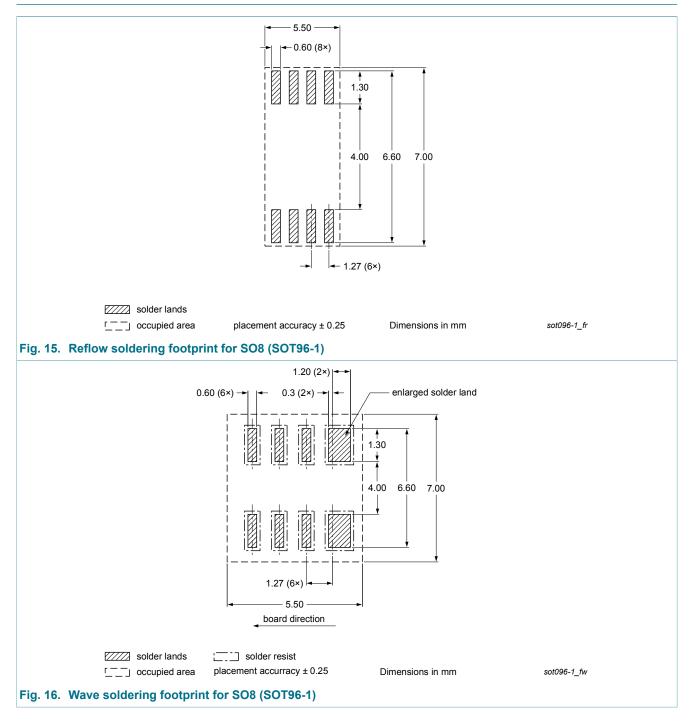
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### 10. Package outline



#### AC Thyristor power switch

## 11. Soldering



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### 12. Legal information

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Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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